

2.5-V PHASE-LOCKED-LOOP CLOCK DRIVER

FEATURES

- Spread-Spectrum Clock Compatible
- Operating Frequency: 60 MHz to 220 MHz
- Low Jitter (Cycle-Cycle): ± 60 ps (± 40 ps at 200 MHz)
- Low Static Phase Offset: ± 50 ps
- Low Jitter (Period): ± 60 ps (± 30 ps at 200 MHz)
- 1-to-4 Differential Clock Distribution (SSTL2)
- Best in Class for $V_{OX} = V_{DD}/2 \pm 0.1$ V
- Operates From Dual 2.6-V or 2.5-V Supplies
- Available in a 28-Pin TSSOP Package
- Consumes < 100 - μ A Quiescent Current
- External Feedback Pins (FBIN, $\overline{\text{FBIN}}$) Are Used to Synchronize the Outputs to the Input Clocks
- Meets/Exceeds JEDEC Standard (JESD82-1) For DDRI-200/266/333 Specification
- Meets/Exceeds Proposed DDRI-400 Specification (JESD82-1A)
- Enters Low-Power Mode When No CLK Input Signal Is Applied or $\overline{\text{PWRDWN}}$ Is Low

APPLICATIONS

- DDR Memory Modules (DDR400/333/266/200)
- Zero-Delay Fan-Out Buffer

DESCRIPTION

The CDCVF855 is a high-performance, low-skew, low-jitter, zero-delay buffer that distributes a differential clock input pair (CLK, $\overline{\text{CLK}}$) to 4 differential pairs of clock outputs (Y[0:3], $\overline{\text{Y}}[0:3]$) and one differential pair of feedback clock outputs (FBOUT, $\overline{\text{FBOUT}}$). The clock outputs are controlled by the clock inputs (CLK, $\overline{\text{CLK}}$), the feedback clocks (FBIN, $\overline{\text{FBIN}}$), and the analog power input (AV_{DD}). When $\overline{\text{PWRDWN}}$ is high, the outputs switch in phase and frequency with CLK. When $\overline{\text{PWRDWN}}$ is low, all outputs are disabled to a high-impedance state (3-state) and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency-detection circuit detects the low-frequency condition and, after applying a >20 -MHz input signal, this detection circuit turns the PLL on and enables the outputs.

When AV_{DD} is strapped low, the PLL is turned off and bypassed for test purposes. The CDCVF855 is also able to track spread-spectrum clocking for reduced EMI.

Because the CDCVF855 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCVF855 is characterized for both commercial and industrial temperature ranges.

AVAILABLE OPTIONS

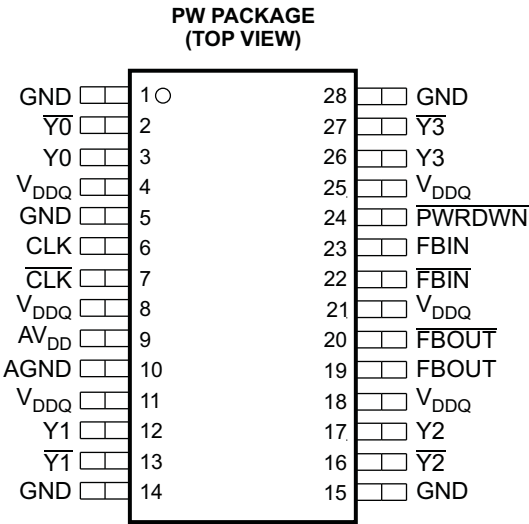
T_A	TSSOP (PW)
-40°C to 85°C	CDCVF855PW



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

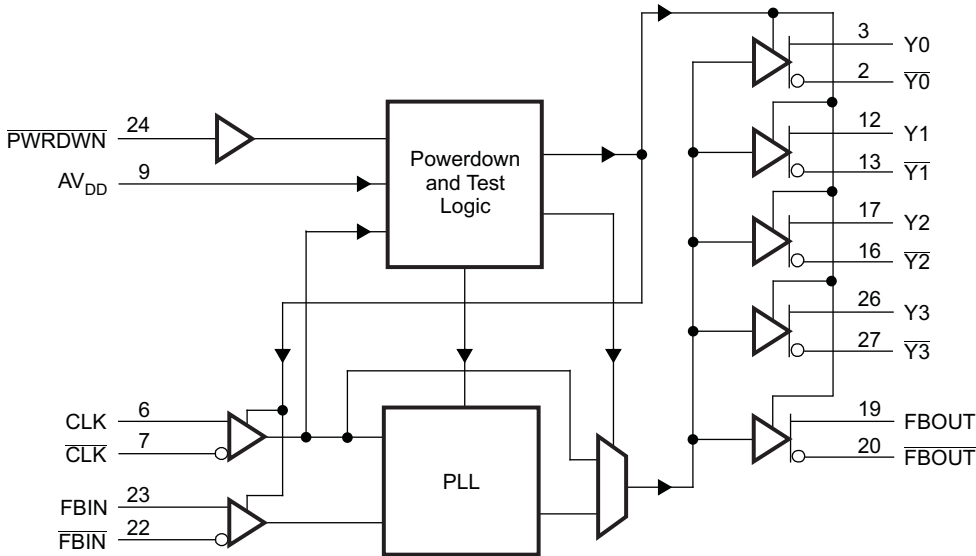
**FUNCTION TABLE
(Select Functions)**

INPUTS				OUTPUTS				PLL
AVDD	PWRDWN	CLK	CLK	Y[0:3]	Y[0:3]	FBOUT	FBOUT	
GND	H	L	H	L	H	L	H	Bypassed/off
GND	H	H	L	H	L	H	L	Bypassed/off
X	L	L	H	Z	Z	Z	Z	Off
X	L	H	L	Z	Z	Z	Z	Off
2.5 V (nom)	H	L	H	L	H	L	H	On
2.5 V (nom)	H	H	L	H	L	H	L	On
2.5 V (nom)	X	<20 MHz	<20 MHz	Z	Z	Z	Z	Off



P0043-02

FUNCTIONAL BLOCK DIAGRAM



B0196-02

Table 2. TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
AGND	10	–	Ground for 2.5-V analog supply
AV _{DD}	9	–	2.5-V analog supply
CLK, $\overline{\text{CLK}}$	6, 7	I	Differential clock input
FBIN, FBIN	22, 23	I	Feedback differential clock input
FBOU, $\overline{\text{FBOU}}$	19, 20	O	Feedback differential clock output
GND	1, 5, 14, 15, 28	–	Ground
PWRDWN	24	I	Output enable for Y and $\overline{\text{Y}}$
V _{DDQ}	4, 8, 11, 18, 21, 25	–	2.5-V supply
$\overline{\text{Y0}}$, Y0	2, 3	O	Buffered output copies of input clock, CLK, $\overline{\text{CLK}}$
Y1, $\overline{\text{Y1}}$	12, 13	O	Buffered output copies of input clock, CLK, $\overline{\text{CLK}}$
$\overline{\text{Y2}}$, Y2	16, 17	O	Buffered output copies of input clock, CLK, $\overline{\text{CLK}}$
Y3, $\overline{\text{Y3}}$	26, 27	O	Buffered output copies of input clock, CLK, $\overline{\text{CLK}}$

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

V _{DDQ} , AV _{DD}	Supply voltage range		0.5 V to 3.6 V
V _I	Input voltage range ⁽²⁾⁽³⁾		–0.5 V to V _{DDQ} + 0.5 V
V _O	Output voltage range ⁽²⁾⁽³⁾		–0.5 V to V _{DDQ} + 0.5 V
I _{IK}	Input clamp current	V _I < 0 or V _I > V _{DDQ}	±50 mA
I _{OK}	Output clamp current	V _O < 0 or V _O > V _{DDQ}	±50 mA
I _O	Continuous output current	V _O = 0 to V _{DDQ}	±50 mA
I _{DDS}	Continuous current to GND or V _{DDQ}		±100 mA
T _{stg}	Storage temperature range		–65°C to 150°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- (3) This value is limited to 3.6 V maximum.

THERMAL CHARACTERISTICS

R _{θJA} for TSSOP Package ⁽¹⁾	
Airflow	High K
0 ft/min (0 m/min)	94.4°C/W
150 ft/min (45.72 m/min)	82.8°C/W

- (1) The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS

				MIN	NOM	MAX	UNIT	
Supply voltage		V _{DDQ}	PC1600 – PC3200		2.3		2.7	V
		AVDD		V _{DDQ} – 0.12		2.7		
V _{IL}	Low-level input voltage	CLK, $\overline{\text{CLK}}$, FBIN, $\overline{\text{FBIN}}$			V _{DDQ} /2 – 0.18			V
		$\overline{\text{PWRDWN}}$			–0.3	0.7		
V _{IH}	High-level input voltage	CLK, $\overline{\text{CLK}}$, FBIN, $\overline{\text{FBIN}}$			V _{DDQ} /2 + 0.18			V
		$\overline{\text{PWRDWN}}$			1.7	V _{DDQ} + 0.3		
DC input signal voltage ⁽¹⁾					–0.3	V _{DDQ} + 0.3		V
V _{ID}	Differential input signal voltage ⁽²⁾	DC	CLK, FBIN	V _{DDQ} = 2.3 V – 2.7V	0.36	V _{DDQ} + 0.6		V
				V _{DDQ} = 2.425 V – 2.7 V	0.25	V _{DDQ} + 0.6		
		AC	CLK, FBIN	V _{DDQ} = 2.3 V – 2.7 V	0.7	V _{DDQ} + 0.6		
				V _{DDQ} = 2.425 V – 2.7 V	0.49	V _{DDQ} + 0.6		
V _{IX}	Input differential pair cross voltage ⁽³⁾⁽⁴⁾				V _{DDQ} /2 – 0.2	V _{DDQ} /2 + 0.2		V
I _{OH}	High-level output current				–12			mA
I _{OL}	Low-level output current				12			mA
SR	Input slew rate				1	4		V/ns
T _A	Operating free-air temperature				–40	85		°C

(1) The unused inputs must be held high or low to prevent them from floating.

(2) The dc input signal voltage specifies the allowable dc execution of the differential input.

(3) The differential input signal voltage specifies the differential voltage |V_{TR} – V_{CP}| required for switching, where V_{TR} is the true input level and V_{CP} is the complementary input level.

(4) The differential cross-point voltage is expected to track variations of V_{CC} and is the voltage at which the differential signals must cross.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK} Input voltage, all inputs	V _{DDQ} = 2.3 V, I _I = –18 mA			–1.2	V
V _{OH} High-level output voltage	V _{DDQ} = min to max, I _{OH} = –1 mA	V _{DDQ} – 0.1			V
	V _{DDQ} = 2.3 V, I _{OH} = –12 mA	1.7			
V _{OL} Low-level output voltage	V _{DDQ} = min to max, I _{OL} = 1 mA			0.1	V
	V _{DDQ} = 2.3 V, I _{OL} = 12 mA			0.6	
V _{OD} Output voltage swing ⁽²⁾	Differential outputs are terminated with 120 Ω, C _L = 14 pF (See Figure 3)	1.1		V _{DDQ} – 0.4	V
V _{OX} Output differential cross-voltage ⁽³⁾		V _{DDQ} /2 – 0.1	V _{DDQ} /2	V _{DDQ} /2 + 0.1	V
I _I Input current	V _{DDQ} = 2.7 V, V _I = 0 V to 2.7 V			±10	μA
I _{OZ} High-impedance-state output current	V _{DDQ} = 2.7 V, V _O = V _{DDQ} or GND			±10	μA
I _{DDPD} Power-down current on V _{DDQ} + AV _{DD}	CLK and $\overline{\text{CLK}}$ = 0 MHz; $\overline{\text{PWRDWN}}$ = Low; Σ of I _{DD} and A _I _{DD}		20	100	μA
A _I _{DD} Supply current on AV _{DD}	f _O = 170 MHz		6	8	mA
	f _O = 200 MHz		8	10	
C _I Input capacitance	V _{DDQ} = 2.5 V, V _I = V _{DDQ} or GND	2	2.5	3.5	pF

(1) All typical values are at a nominal V_{DDQ}.

(2) The differential output signal voltage specifies the differential voltage |V_{TR} – V_{CP}|, where V_{TR} is the true output level and V_{CP} is the complementary output level.

(3) The differential cross-point voltage tracks variations of V_{DDQ} and is the voltage at which the differential signals must cross.

ELECTRICAL CHARACTERISTICS (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
I _{DD}	Dynamic current on V _{DDQ}	Without load	f _O = 170 MHz		65	80	mA
			f _O = 200 MHz		75	90	
		Differential outputs terminated with 120 Ω, C _L = 0 pF	f _O = 170 MHz		110	140	
			f _O = 200 MHz		120	150	
		Differential outputs terminated with 120 Ω, C _L = 14 pF	f _O = 170 MHz		130	160	
			f _O = 200 MHz		140	170	
ΔC	Part-to-part input capacitance variation	V _{DDQ} = 2.5 V, V _I = V _{DDQ} or GND				1	pF
C _{I(Δ)}	Input capacitance difference between CLK and \overline{CLK} , FBIN and \overline{FBIN}	V _{DDQ} = 2.5 V, V _I = V _{DDQ} or GND				0.25	pF

TIMING REQUIREMENTS

over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		MIN	MAX	UNIT
f_{CLK}	Operating clock frequency	60	220	MHz
	Application clock frequency	90	220	
Input clock duty cycle		40%	60%	
Stabilization time (PLL mode) ⁽¹⁾			10	μ s
Stabilization time (bypass mode) ⁽²⁾			30	ns

(1) The time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK and V_{DD} must be applied. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

(2) A recovery time is required when the device goes from power-down mode into bypass mode (AV_{DD} at GND).

SWITCHING CHARACTERISTICS

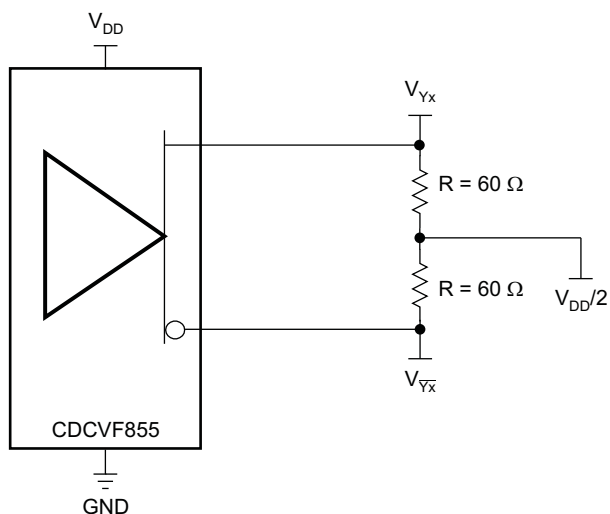
over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}^{(1)}$ Low- to high-level propagation delay time	Test mode/CLK to any output		3.5		ns
$t_{PHL}^{(1)}$ High- to low-level propagation delay time	Test mode/CLK to any output		3.5		ns
$t_{jit(per)}^{(2)}$ Jitter (period), see Figure 7	100/133/167 MHz (PC1600/2100/2700)	–65		65	ps
	200 MHz (PC3200)	–30		30	
$t_{jit(cc)}^{(2)}$ Jitter (cycle-to-cycle), see Figure 4	100/133/167 MHz (PC1600/2100/2700)	–60		60	ps
	200 MHz (PC3200)	–40		40	
$t_{jit(hper)}^{(2)}$ Half-period jitter, see Figure 8	100/133/167 MHz (PC1600/2100/2700)	–100		100	ps
	200 MHz (PC3200)	–75		75	
$t_{slr(o)}$ Output clock slew rate, see Figure 9	Load: 120 Ω , 14 pF	1		2	V/ns
t_{ϕ} Static phase offset, see Figure 5	100/133/167/200 MHz	–50		50	ps
$t_{sk(o)}$ Output skew, see Figure 6	Load: 120 Ω , 14 pF; 100/133/167/200 MHz			40	ps

(1) Refers to the transition of the noninverting output.

(2) This parameter is assured by design but cannot be 100% production tested.

PARAMETER MEASUREMENT INFORMATION



S0229-02

Figure 1. IBIS Model Output Load

PARAMETER MEASUREMENT INFORMATION (continued)

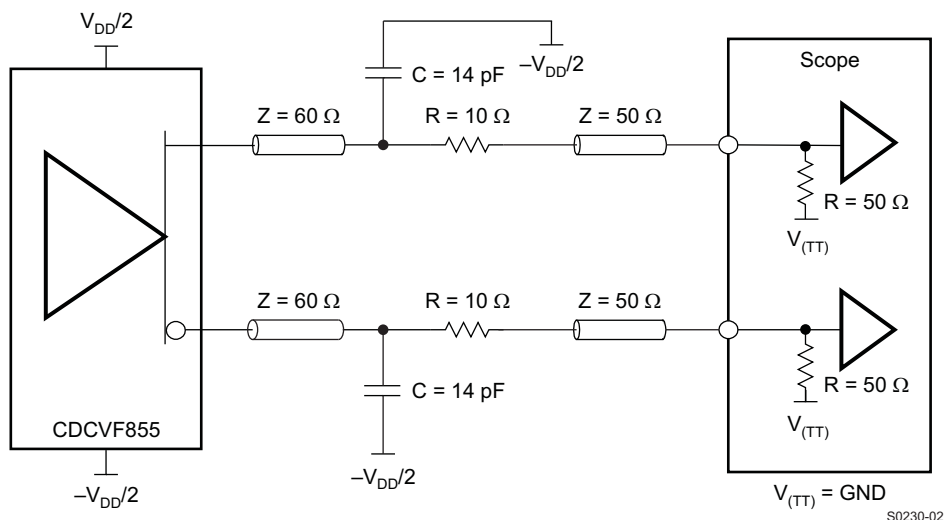


Figure 2. Output Load Test Circuit

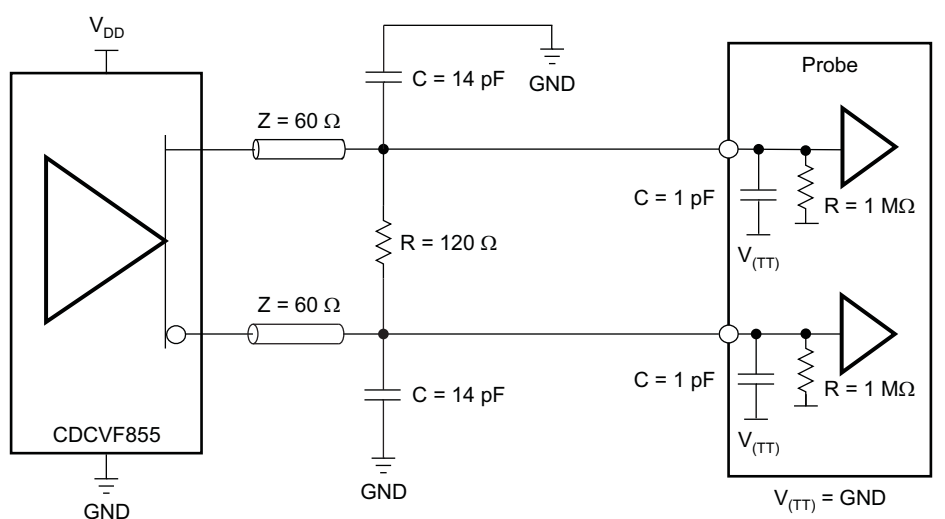
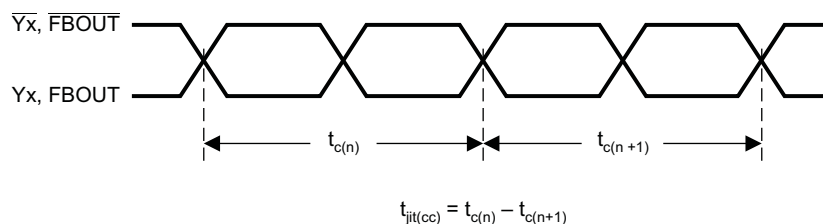
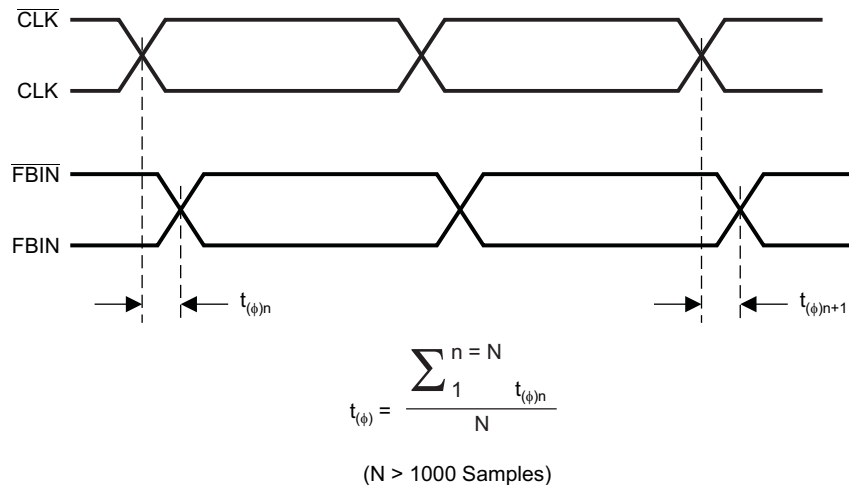


Figure 3. Output Load Test Circuit for Crossing Point

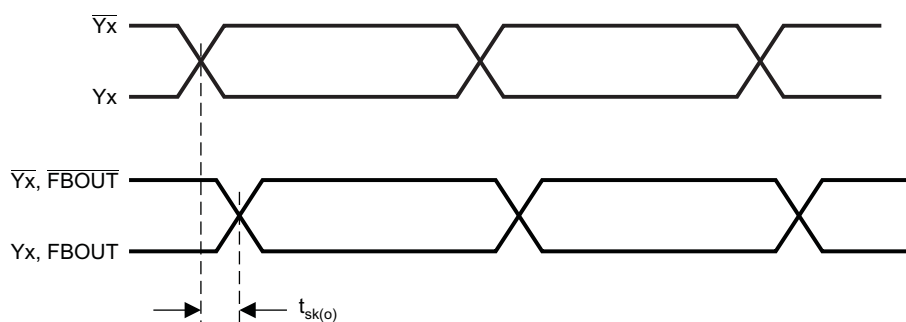


T0174-01

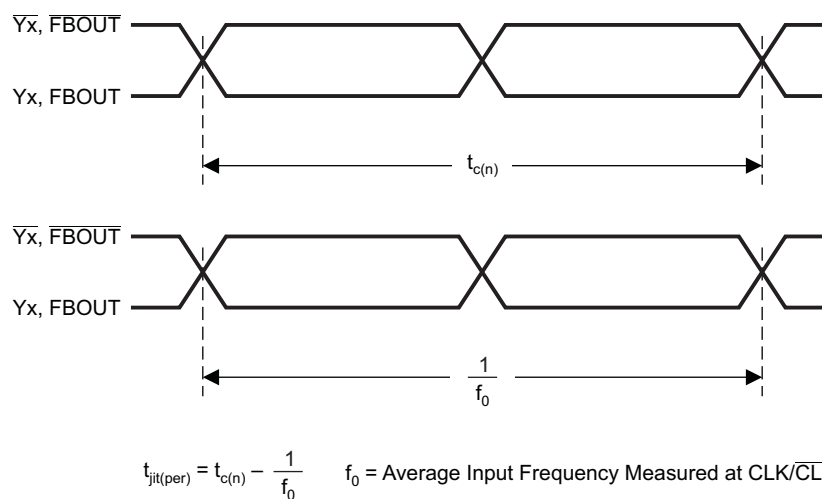
Figure 4. Cycle-to-Cycle Jitter

PARAMETER MEASUREMENT INFORMATION (continued)

T0175-01

Figure 5. Phase Offset

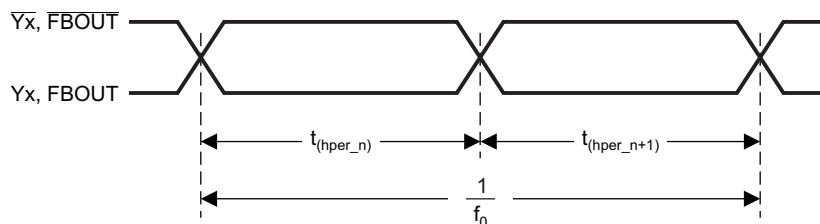
T0176-01

Figure 6. Output Skew

T0177-01

Figure 7. Period Jitter

PARAMETER MEASUREMENT INFORMATION (continued)

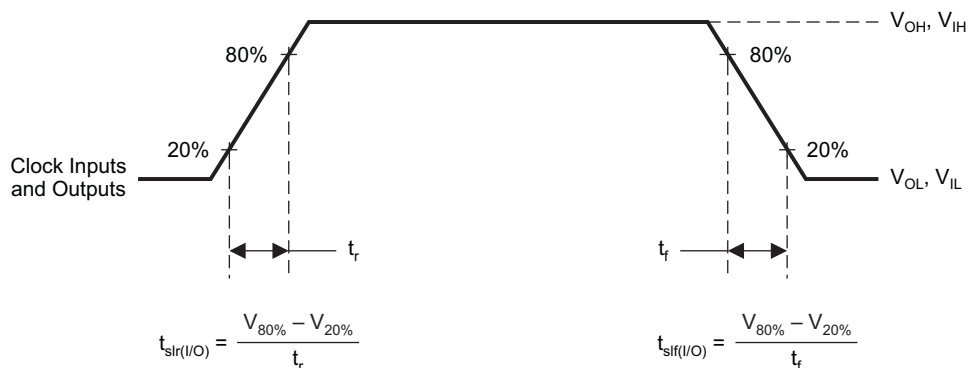


$$t_{jit(hper)} = t_{hper_n} - \frac{1}{2 \times f_0}$$

$n = \text{Any Half Cycle}$
 $f_0 = \text{Average Input Frequency Measured at CLK}/\overline{\text{CLK}}$

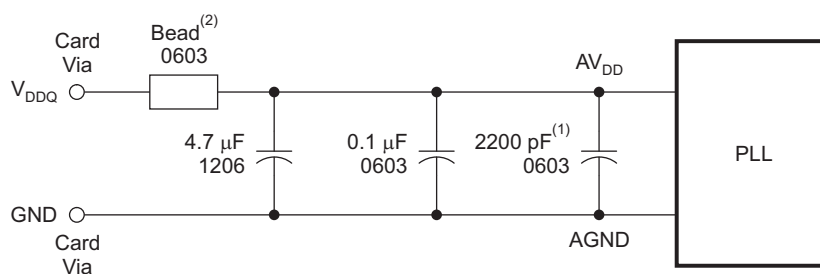
T0178-01

Figure 8. Half-Period Jitter



T0179-01

Figure 9. Input and Output Slew Rates



S0232-01

(1) Place the 2200-pF capacitor close to the PLL.

(2) Recommended bead: Fair-Rite P/N 2506036017Y0 or equivalent (0.8 Ω dc maximum, 600 Ω at 100 MHz).

NOTE: Use a wide trace for the PLL analog power and ground. Connect PLL and capacitors to AGND trace and connect trace to one GND via (farthest from the PLL).

Figure 10. Recommended AV_{DD} Filtering

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
CDCVF855PW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		CDCVF855	Samples
CDCVF855PWG4	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		CDCVF855	Samples
CDCVF855PWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		CDCVF855	Samples
CDCVF855PWGR4	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		CDCVF855	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

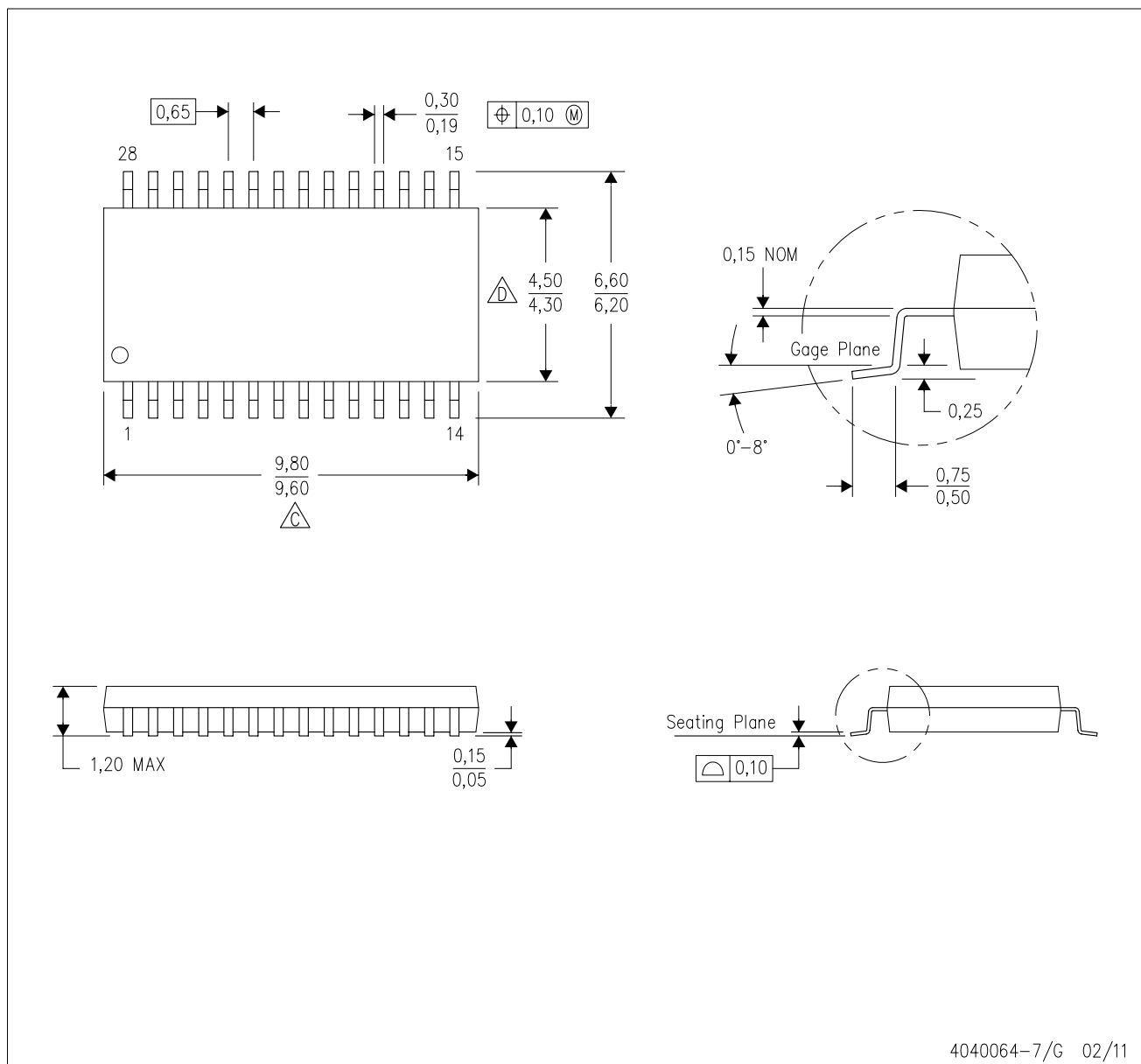
(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE

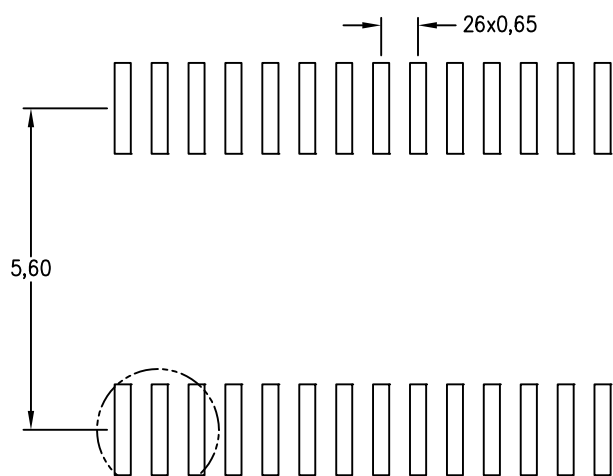


- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

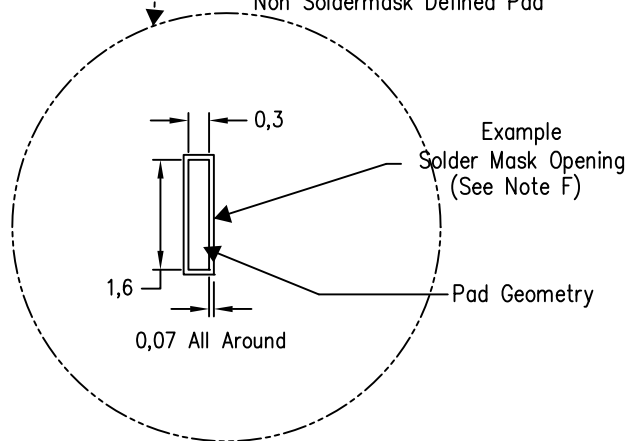
PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE

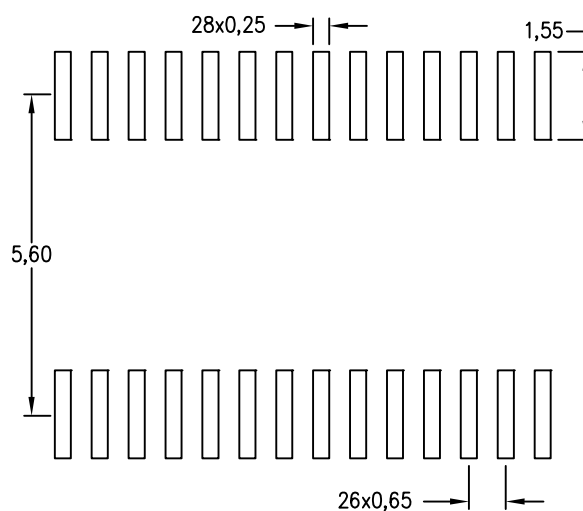
Example Board Layout



Example Non Soldermask Defined Pad



Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).



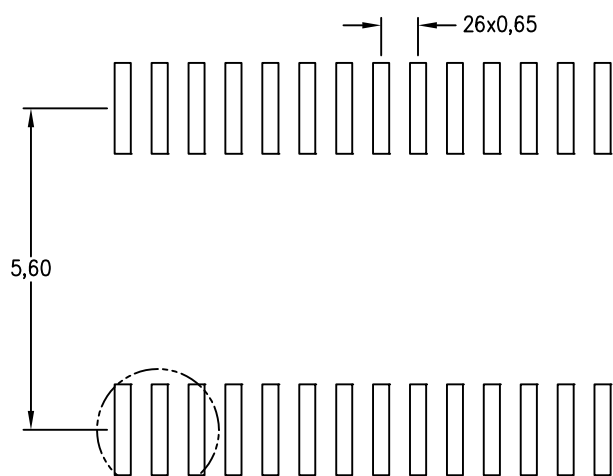
4211284-6/F 12/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

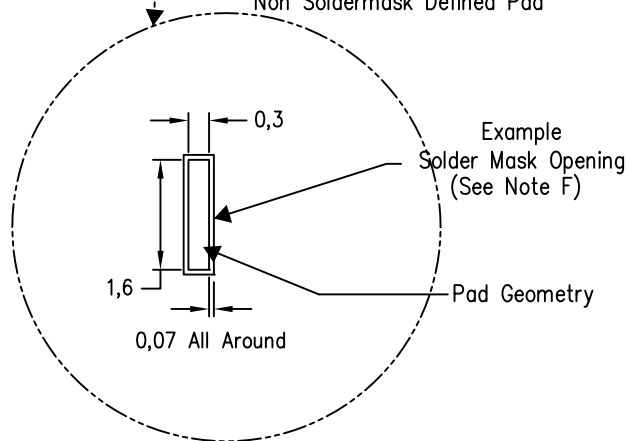
PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE

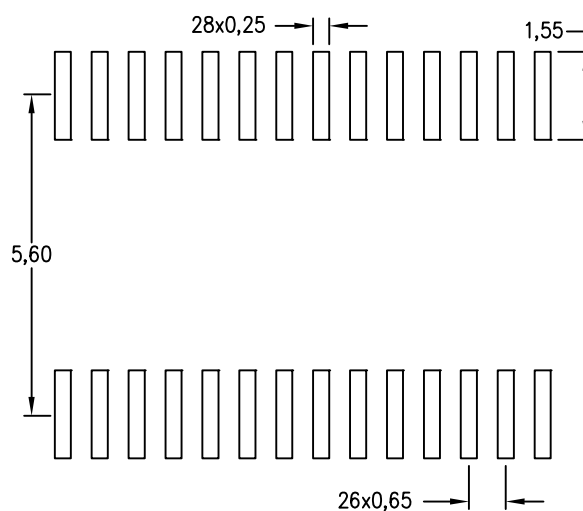
Example Board Layout



Example
Non Soldermask Defined Pad



Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).



4211284-6/F 12/12

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate design.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.